# VS-VSKDS408/060

**Vishay Semiconductors** 



AAP Gen 7 (TO-240AA) Power Modules Schottky Rectifier, 400 A



AAP Gen 7 (TO-240AA)

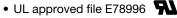
PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub> 400 A				
V <sub>R</sub>	60 V			
Package	AAP Gen 7 (TO-240AA)			
Circuit configuration Two diodes doubler circuit				

### **MECHANICAL DESCRIPTION**

The AAP Gen 7, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

### FEATURES

- 150 °C T<sub>J</sub> operation
- Low forward voltage drop
- High frequency operation
- Low thermal resistance



- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### BENEFITS

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- High surge capability
- Easy mounting on heatsink

### **ELECTRICAL DESCRIPTION / APPLICATIONS**

The VS-VSKDS408.. Schottky rectifier doubler has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature.

Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I <sub>F(AV)</sub>	Rectangular waveform	400	A		
V <sub>RRM</sub>		60	V		
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	25 500	А		
V <sub>F</sub>	200 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.71	V		
TJ	Range	-55 to +150	C°		

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-VSKDS408/060	UNITS		
Maximum DC reverse voltage	V <sub>R</sub>	60	M		
Maximum working peak reverse voltage	V <sub>RWM</sub>	00	V		

RoHS COMPLIANT

Revision: 03-May-17

Document Number: 94643

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ABSOLUTE MAXIMUM RATINGS						
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current per mo		I	50 % duty cycle at $T_{C}$ = 102 °C, rectangular waveform		400	
		IF(AV)			200	
Maximum peak one cycle			5 $\mu s$ sine or 3 $\mu s$ rect. pulse	Following any rated load condition and	25 500	A
non-repetitive surge current		IFSM	10 ms sine or 6 ms rect. pulse	with rated V <sub>RRM</sub> applied	3300	
Non-repetitive avalanche energy		E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 5.5 A, L = 1 mH		15	mJ
Repetitive avalanche current		I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical 1		А	

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V <sub>FM</sub>	200 A	T <sub>J</sub> = 25 °C	0.74	v
		400 A		1.09	
		200 A	- T <sub>J</sub> = 125 °C	0.71	
		400 A		1.02	
Maximum rayaraa laakaga aurrant	I <sub>RM</sub>	T <sub>J</sub> = 25 °C	V <sub>R</sub> = Rated V <sub>R</sub>	2.2	mA
Maximum reverse leakage current		T <sub>J</sub> = 125 °C		1000	mA
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		11 000	pF
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body		5.0	nH
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs
Maximum RMS insulation voltage	V <sub>INS</sub>	50 Hz		3000 (1 min) 3600 (1 s)	V

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-55 to +150	°C
Maximum thermal resistance, junction to case per leg		R <sub>thJC</sub>	DC operation	0.26	°C/W
Typical thermal resistance, case to heatsink per module		R <sub>thCS</sub>		0.1	0/00
Approximate weight				75	g
Approximate weight				2.7	oz.
Mounting torque ± 10 %	to heatsink		A mounting compound is recommended and the torque should be rechecked after a period of 3 h to allow for the	4	Nm
busbar			spread of the compound.	3	
Case style			JEDEC®	TO-240AA co	ompatible



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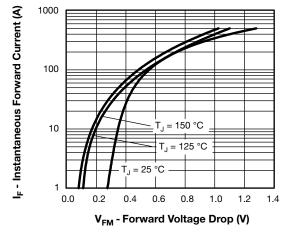


Fig. 1 - Maximum Forward Voltage Drop Characteristics

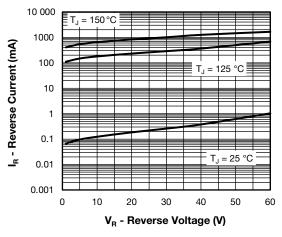


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

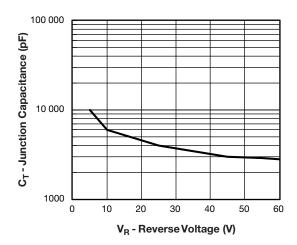


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

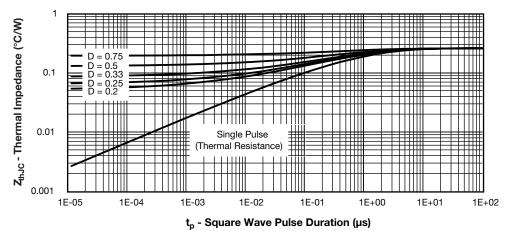


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

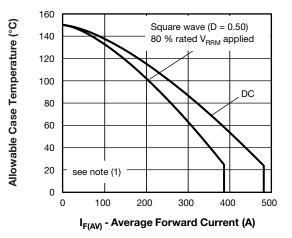
 Revision: 03-May-17
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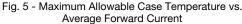
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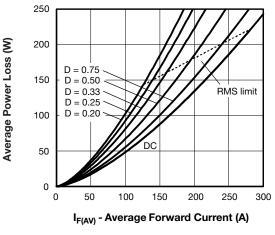




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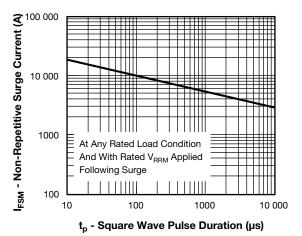


Fig. 7 - Maximum Non-Repetitive Surge Current

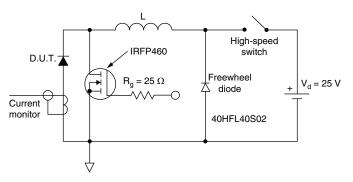


Fig. 8 - Unclamped Inductive Test Circuit

#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ \mathsf{x} \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ \mathsf{x} \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \ - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$ 

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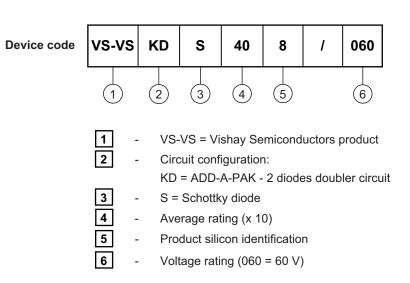
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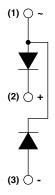
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### **ORDERING INFORMATION TABLE**



#### **CIRCUIT CONFIGURATION**



LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?95369					

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# **ADD-A-PAK Generation VII - Diode**

### **DIMENSIONS** in millimeters (inches)





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Revision: 01-Jul-2024